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|  | <p>SI7738DP-T1-GE3</p> |
| | <p>Hersteller-Teilenummer: SI7738DP-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 150V 30A PPAK SO-8</p> <p>Datenblätter:  SI7738DP-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 8473 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | SI7738DP-T1-GE3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 150V 30A PPAK SO-8 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 8473 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | PowerPAK® SO-8 |
| Supplier Device-Gehäuse | PowerPAK® SO-8 |
| Verlustleistung (max) | 5.4W (Ta), 96W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 150V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 30A (Tc) |
| Rds On (Max) @ Id, Vgs | 38 mOhm @ 7.7A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 53nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 2100pF @ 75V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |

SI7738DP-T1-GE3 ist neu im Original, Suche SI7738DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7738DP-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7738DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

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|  SI7738DP SI SI7738DP SI |  SI7738DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 30A PPAK SO-8 |  SI7742DP SI SI7742DP SI |  SI7742DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 60A PPAK SO-8 |
|  SI7738DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 150V 30A PPAK SO-8 |  SI7742DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 60A PPAK SO-8 |  SI7738DP-T1-3 Vishay Precision Group SI7738DP-T1-3 VISHAY |  SI7738DP-T1-E3 Vishay / Siliconix MOSFET N-CH 150V 30A PPAK SO-8 |

heiße Teile

Mehr

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| <ul style="list-style-type: none"> ⊕ SI7703EDN-T1-GE3 ⊖ SI7705DN-T1-E3 ⊕ SI7716ADN-TI-GE3 D SI7726DN ⇒ SI7738DP ↔ SI7742DP-T1-E3 ⊕ SI7758DP ⊖ SI7774DP-T1-GE3 ⊕ SI7788DP-T1-GE3 ↔ SI7792DP-T1-GE3 | <ul style="list-style-type: none"> ↔ SI7703EDN-T1-GE3 ⊕ SI7716ADN ⊖ SI7716DN-T1-GE3 ⊕ SI7726DN-T1-E3 ↔ SI7738DP-T1-3 ⇒ SI7742DP-T1-GE3 D SI7758DP-T1-GE3 ⊕ SI7774DP-T1-GE3 ⊖ SI7790DP-T1-E3 ⊕ SI7794DP-T1-GE3 | <ul style="list-style-type: none"> ⇒ SI7703EDN-TI-E3 D SI7716ADN-T1-E3 ⊕ SI7720DN-T1-E3 ⊖ SI7726DN-T1-GE3 ⊕ SI7738DP-T1-E3 D SI7742DP-T1-GE3 ⇒ SI7758DP-T1-GE3 ↔ SI7784DP-T1-GE3 ⊕ SI7790DP-T1-GE3 ⊖ SI7794DP-T1-GE3 | <ul style="list-style-type: none"> D SI7705DN ⇒ SI7716ADN-T1-GE3 ↔ SI7720DN-T1-GE3 ⊕ SI7726DN-T1-GE3 ⊖ SI7738DP-T1-E3 ⊕ SI7748DP-T1-GE3 ↔ SI7772DP-T1-GE3 ⇒ SI7784DP-T1-GE3 D SI7790DP-T1-GE3 ⊕ SI7798DP-T1-GE3 | <ul style="list-style-type: none"> ⇒ SI7705DN-T1 ⇒ SI7716ADN-T1-GE3 ⇒ SI7720DN-T1-GE3 ⇒ SI7732DP-T1-GE3 ⇒ SI7738DP-T1-GE3 ⊖ SI7748DP-T1-GE3 ⇒ SI7772DP-T1-GE3 ⇒ SI7788DP-T1-GE3 ⇒ SI7792DP-T1-GE3 ⇒ SI7804DN |
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